



## High EB High DC gain Ultra-Small package switch transistor

### Feature

This device is Pb-Free, Halogen Free/BFR Free and RoHS compliant.

Package: SOT-23

Emitter -Base Breakdown Voltage 11V

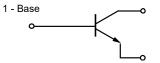
> High DC current gain typical 380

Low Saturation Voltage 80mv

> 0.15 continuous collector current

> NPN switch transistor

3 - Collector



2 - Emitter

### **Mechanical Characteristics**

Lead finish:100% matte Sn(Tin)

Mounting position: Any

Qualified max reflow temperature:260°C

Device meets MSL 1 requirements

Pure tin plating: 7 ~ 17 um

Pin flatness:≤3mil

## Electrical characteristics per line@25℃( unless otherwise specified)

Parameter	Symbol	Value	Units
Collector-Emitter Breakdown Voltage	V (BR)CEO	50	V
Collector-Base Breakdown Voltage	V (BR)CBO	80	V
Emitter -Base Breakdown Voltage	V (BR)EBO	11	V
Collector Current	Ic	0.15	А
Total Dissipation @25°C	P <sub>tot</sub>	0.15	W
Storage Temperature	T <sub>stg</sub>	-65~150	°C
Max. Operating Junction Temperature	Tj	150	°C

### Absolute maximum rating@25℃

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Collector-Base Breakdown Voltage	ВУсво	I <sub>C</sub> =50uA	80			٧
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	Ic=1mA	50			V
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	I <sub>E</sub> =50uA		11		V
Collector Cut-off Current (I <sub>E</sub> =0)	I <sub>CBO</sub>	V <sub>CB</sub> =60V			0.1	μΑ
Emitter Cut-off Current(Ic=0)	I <sub>EBO</sub>	V <sub>EB</sub> =7V			0.1	μΑ
DC Current Gain	h <sub>FE</sub>	I <sub>C</sub> =1mA,V <sub>CE</sub> =6V	200		560	-
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =50mA,I <sub>B</sub> =5mA	-	0.08		٧
Transition frequency	f⊤	V <sub>CE</sub> =12V,I <sub>E</sub> =-2mA,f=100MHz		200		MHz
Output Capacitance	Cob	V <sub>CE</sub> =12V,I <sub>E</sub> =0mA,f=1MHz		2	3.5	pF

### **Typical Characteristics**

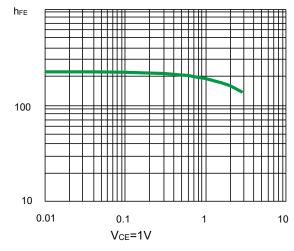


Fig1.DC Current Gain

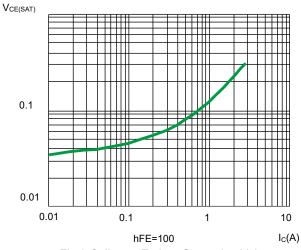


Fig 3.Collector-Emitter Saturation Voltage

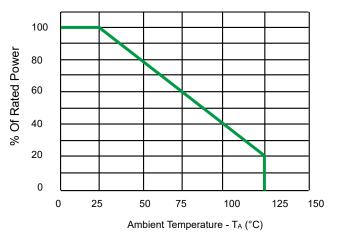


Fig2. Power Derating Curve

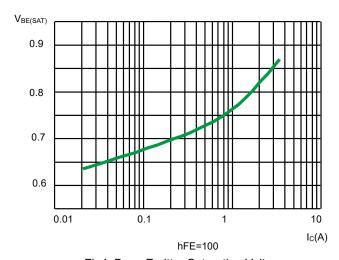


Fig4. Base-Emitter Saturation Voltage

## High EB High DC gain Ultra-Small package switch transistor PNT23T503E0-2

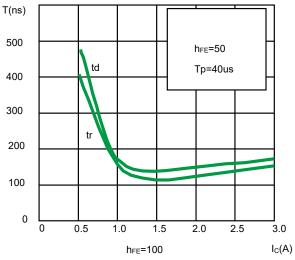


Fig 5.Switching Times Resistive Load

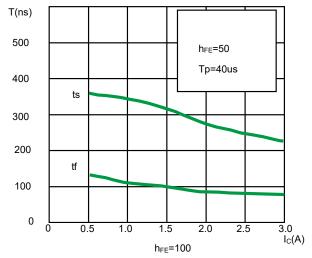
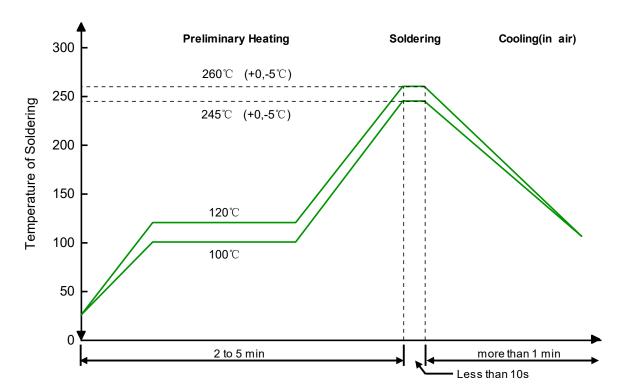


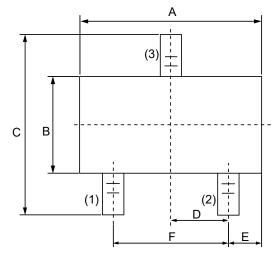
Fig6. Switching Times Resistive Load

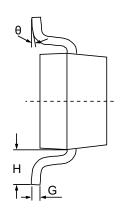
## **Solder Reflow Recommendation**

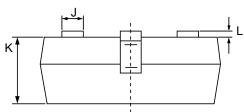


Remark: Pb free for 260°C; Pb for 245°C.

## Product dimension(SOT-23)

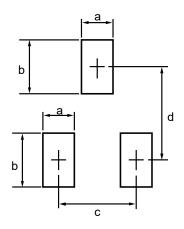






Dim	Millimeters		Inches		
Dim	MIN	MAX	MIN	MAX	
А	2.80	3.00	0.1102	0.1197	
В	1.20	1.40	0.0472	0.0551	
С	2.10	2.50	0.0830	0.0984	
D	0.89	1.02	0.0350	0.0401	
E	0.45	0.60	0.0177	0.0236	
F	1.78	2.04	0.0701	0.0807	
G	0.085	0.177	0.0034	0.0070	
Н	0.45	0.60	0.0180	0.0236	
J	0.37	0.50	0.0150	0.0200	
К	0.89	1.11	0.0350	0.0440	
L	0.013	0.100	0.0005	0.0040	
θ	0°	10°	0°	10°	

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Dim	Millimeters		
Dim	MIN	MAX	
а		0.7	
b		1.2	
С		2.04	
d		2.2	

## Ordering information

Device	Package	Shipping		
PNT23T503E0-2	SOT-23 (Pb-Free)	3000 / Tape & Reel		

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